**Vishay Semiconductors** 

RoHS

## High Voltage, Input Rectifier Diode, 10 A



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## LINKS TO ADDITIONAL RESOURCES



PRIMARY CHARACTERISTICS							
I <sub>F(AV)</sub>	10 A						
V <sub>R</sub>	1200 V						
V <sub>F</sub> at I <sub>F</sub>	1.1 V						
I <sub>FSM</sub>	160 A						
T <sub>J</sub> max.	150 °C						
Package	TO-220AC 2L						
Circuit configuration	Single						

## FEATURES

- Glass passivated pellet chip junction
- Meets JESD 201 class 1A whisker test
- Flexible solution for reliable AC power COMPLIANT HALOGEN
  rectification
- High surge, low V<sub>F</sub> rugged blocking diode for DC charging stations
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishav.com/doc?99912</u>

## APPLICATIONS

- On-board and off-board EV/HEV battery chargers
- Input rectification

### DESCRIPTION

High voltage rectifiers optimized for very low forward voltage drop with moderate leakage.

These devices are intended for use in main rectification (single or three phase bridge).

OUTPUT CURRENT IN TYPICAL APPLICATIONS								
APPLICATIONS	SINGLE-PHASE BRIDGE	THREE-PHASE BRIDGE	UNITS					
Capacitive input filter $T_A = 55$ °C, $T_J = 125$ °C common heatsink of 1 °C/W	12.0	16.0	А					

MAJOR RATINGS AND CHARACTERISTICS										
SYMBOL	CHARACTERISTICS	VALUES	UNITS							
I <sub>F(AV)</sub>	Sinusoidal waveform	10	А							
V <sub>RRM</sub>		1200	V							
I <sub>FSM</sub>		160	А							
V <sub>F</sub>	10 A, T <sub>J</sub> = 25 °C	1.1	V							
TJ		-40 to +150	O°							

VOLTAGE RATINGS			
PART NUMBER	V <sub>RRM</sub> , MAXIMUM PEAK REVERSE VOLTAGE V	V <sub>RSM</sub> , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I <sub>RRM</sub> AT 150 °C mA
VS-10ETS12THM3	1200	1300	0.5

ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum average forward current	I <sub>F(AV)</sub>	$T_C = 105 \text{ °C}, 180^\circ \text{ conduction half sine wave}$	10					
Maximum peak one cycle	I	10 ms sine pulse, rated V <sub>RRM</sub> applied	135	А				
non-repetitive surge current	IFSM	10 ms sine pulse, no voltage reapplied	160					
Maximum I <sup>2</sup> t for fusing	l <sup>2</sup> t	10 ms sine pulse, rated V <sub>RRM</sub> applied	91	A <sup>2</sup> s				
Maximum Frior fusing	1-1	10 ms sine pulse, no voltage reapplied 130		A-5				
Maximum I <sup>2</sup> √t for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied	1300	A²√s				

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# VS-10ETS12THM3



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ELECTRICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CO	VALUES	UNITS				
Maximum forward voltage drop	V <sub>FM</sub>	10 A, T <sub>J</sub> = 25 °C	1.1	V				
Forward slope resistance	r <sub>t</sub>	T, = 150 °C	20	mΩ				
Threshold voltage	V <sub>F(TO)</sub>	1j = 150 C	$I_{\rm J} = 150  {}^{\circ}{\rm C}$					
Maximum rayaraa laakaga ayrrant		T <sub>J</sub> = 25 °C	$V_{B} = Rated V_{BBM}$	0.05	m ^			
Maximum reverse leakage current	IRM	T <sub>J</sub> = 150 °C	VR = naled VRRM	0.50	mA			

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Maximum junction and storage temperature range	T <sub>J</sub> , T <sub>Stg</sub>		-40 to +150	°C				
Maximum thermal resistance, junction to case	R <sub>thJC</sub>	DC operation	2.5					
Maximum thermal resistance, junction to ambient (PCB mount)	R <sub>thJA</sub>		62	°C/W				
Soldering temperature	Ts		240	°C				
Approximate weight			2	g				
Approximate weight			0.07	oz.				
Marking device		Case style TO-220AC 2L	10ETS	512TH				

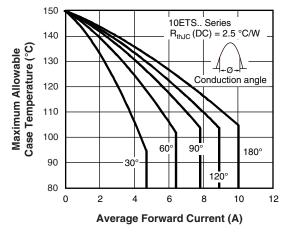


Fig. 1 - Current Rating Characteristics

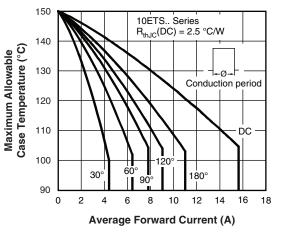


Fig. 2 - Current Rating Characteristics





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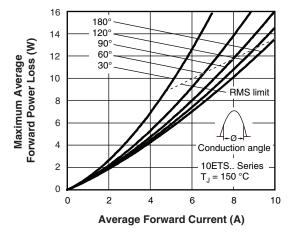


Fig. 3 - Forward Power Loss Characteristics

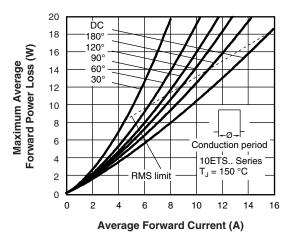
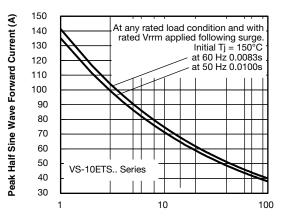


Fig. 4 - Forward Power Loss Characteristics



Number of Equal Amplitude Half Cycle Current Pulses (N)

Fig. 5 - Maximum Non-Repetitive Surge Current

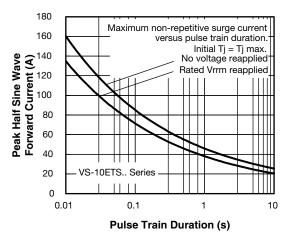


Fig. 6 - Maximum Non-Repetitive Surge Current

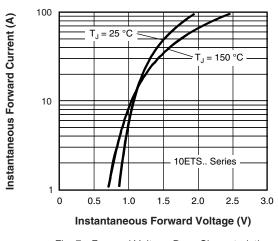


Fig. 7 - Forward Voltage Drop Characteristics

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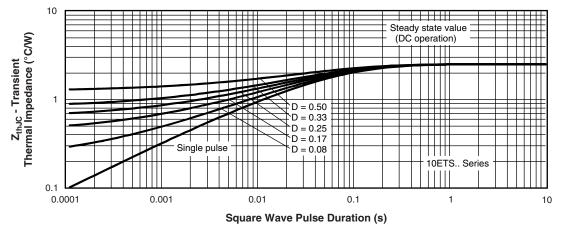


Fig. 8 - Thermal Impedance Z<sub>thJC</sub> Characteristics

## **ORDERING INFORMATION TABLE**

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SHA

Device code	VS-	10	Е	т	s	12	т	н	МЗ
	(1)	(2)	(3)	(4)	(5)	(6)	(7)	(8)	(9)
	1.	· Visł	nay Sem	niconduc	ctors pro	oduct			
	2 -	Cur	rent rati	ng (10 =	10 A)				
	3 -	Circ	uit conf	figuratio	n:				
		E =	2L TO-2	220AC					
	4 -	Pac	kage:						
		T = 1	TO-220						
	5 -	Тур	e of silio	con:					
		S =	standar	d recove	ery recti	fier			
	6 -	· Volt	age coo	de x 100	$= V_{RRN}$	1	12 =	= 1200 \	V
	7 -	• N	one = T	0-220AI	В				
		• T	= true p	oin TO-2	20				
	8 -	• H=	AEC-Q	101 qua	lified				
	9 -	Env	ironmen	ital digit:					
		М3	= halog	en-free,	RoHS-	complia	ant, and	termina	ations le

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-10ETS12THM3	50	1000	Antistatic plastic tubes					

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?96069					
Part marking information	www.vishay.com/doc?95391					
SPICE model	www.vishay.com/doc?97334					

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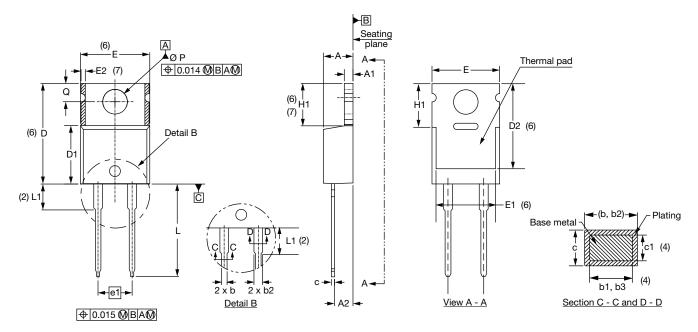
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TO-220AC 2L

### **DIMENSIONS** in millimeters and inches



SYMBOL	MILLIMETERS		INC	HES	NOTES	SYMBOL	MILLIN	IETERS	INC	HES	NOTES	
STNIDUL	MIN.	MAX.	MIN.	MAX.	NOTES		STIVIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.25	4.65	0.167	0.183			E1	6.86	8.89	0.270	0.350	6
A1	1.14	1.40	0.045	0.055			E2	-	0.76	-	0.030	7
A2	2.56	2.92	0.101	0.115			e1	4.88	5.28	0.192	0.208	
b	0.69	1.01	0.027	0.040			H1	5.84	6.86	0.230	0.270	6, 7
b1	0.38	0.97	0.015	0.038	4		L	13.52	14.02	0.532	0.552	
b2	1.20	1.73	0.047	0.068			L1	3.32	3.82	0.131	0.150	2
b3	1.14	1.73	0.045	0.068	4		ØΡ	3.54	3.73	0.139	0.147	
с	0.36	0.61	0.014	0.024			Q	2.60	3.00	0.102	0.118	
c1	0.36	0.56	0.014	0.022	4							
D	14.85	15.25	0.585	0.600	3							
D1	8.38	9.02	0.330	0.355								
D2	11.68	12.88	0.460	0.507	6							
E	10.11	10.51	0.398	0.414	3, 6							

Notes

<sup>(1)</sup> Dimensioning and tolerancing as per ASME Y14.5M-1994

<sup>(2)</sup> Lead dimension and finish uncontrolled in L1

(3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

(4) Dimension b1, b3 and c1 apply to base metal only

<sup>(5)</sup> Controlling dimension: inches

<sup>(6)</sup> Thermal pad contour optional within dimensions E, H1, D2 and E1

<sup>(7)</sup> Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed

<sup>(8)</sup> Outline conforms to JEDEC<sup>®</sup> TO-220, except D2, where JEDEC<sup>®</sup> minimum is 0.480"

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